

# TCC Available NAND List V8

Rev. 1.06

Telechips

## MLC Type NAND-Flash Memory List

Product		NAND Driver Version	NAND Features											
Vendor	Part Number		ECC (Bit/Byte)	Bus Width (Bit)	Access Time (ns)	CS	Data (Byte)	Spare (Byte)	PpB	Block Size (KB)	Max Bad Block	Total Block	Function	Total Size (MB)
Hynix	H27UAG8T2B	V8.7.16	24/1024	8	25	x1	8192	448	256	2048	25	1024	CR,MP	2048
Hynix	H27UBG8T2A	V8.0.0	24/1024	8	25	x1	8192	448	256	2048	25	2048	CR,MP	4096
Samsung	K9GAG08U0E	V8.34.51	24/1024	8	30	x1	8192	436	128	1024	58	2076	CR,CP	2076
Samsung	K9GBG08U0A <sup>1)</sup>	V8.28.42	24/1024	8	25	x1	8192	640	128	1024	116	4152	CR,CP,MP,RAND	4152
Samsung	K9LCG08U0A <sup>1)</sup>	V8.34.51	24/1024	8	25	x1	8192	640	128	1024	116	8304	CR,CP,MP,RAND	8304
Toshiba	TC58NVG4D2HTA00	V8.34.51	40/1024	8	20	x1	8192	640	128	1024	58	2056	CR,CP,RAND	2056
Toshiba	TC58NVG5D2HTA00	V8.34.51	40/1024	8	20	x1	8192	640	128	1024	80	4116	CR,CP,MP,RAND	4116
Toshiba	THGVR1G5D1HTA00	V8.51.69	embeded	8	30	x1	8192	32	128	1024	90	4116	CR,CP,MP	4116
Toshiba	TC58NVG6D2GTA00	V8.34.51	40/1024	8	25	x1	8192	640	256	2048	128	4124	CR,CP,MP,RAND	8248
Toshiba	THGVR1G6D1GTA00	V8.51.69	embeded	8	30	x1	8192	32	256	2048	138	4124	CR,CP,MP	8248
Micron	MT29F32G08CBACA	V8.34.51	24/1024	8	25	x1	4096	224	256	1024	100	4096	CR,CP,MP	4096
Micron	MT29F64G08CBAAA	V8.34.51	24/1024	8	25	x1	8192	448	256	2048	100	4096	CR,CP,MP	8192
Micron	MT29F64G08CBABA <sup>2)</sup>	V8.56.81	40/1024	8	25	x1	8192	744	256	2048	100	4096	CR,CP,MP,RR	8192
Hynix	H27UBG8T2B	TBD	~ 2012/11/30	-	-	-	-	-	-	-	-	-	-	-
Samsung	K9GAG08U0F	TBD	~ 2012/11/30	-	-	-	-	-	-	-	-	-	-	-
Samsung	K9GBG08U0B	TBD	~ 2012/11/30	-	-	-	-	-	-	-	-	-	-	-

1) Pin is not 100% compatible with normal NAND.

2) TCC8920/8923/8925 support these NAND with 24bit/512B ECC condition. Please contact to NAND manufacturer for detailed information.

## SLC Type NAND-Flash Memory List

Product		NAND Driver Version	NAND Features											
Vendor	Part Number		ECC (Bit/Byte)	Bus Width (Bit)	Access Time (ns)	CS	Data (Byte)	Spare (Byte)	PpB	Block Size (KB)	Max Bad Block	Total Block	Function	Total Size (MB)
Hynix	H27U1G8F2B <sup>1)</sup>	V8.5.8	1/528	8	25	x1	2048	64	64	128	20	1024	CR	128
Samsung	K9F1G08U0D <sup>1)</sup>	V8.18.26	1/528	8	25	x1	2048	64	64	128	20	1024	-	128
Spansion	S34ML01G1 <sup>1)</sup>	V8.56.82	1/528	8	25	x1	2048	64	64	128	20	1024	CR	128
Hynix	H27U2G8F2C <sup>1)</sup>	V8.5.9	1/528	8	25	x1	2048	64	64	128	40	2048	CR,MP	256
Samsung	K9F2G08U0C <sup>1)</sup>	V8.34.51	1/528	8	25	x1	2048	64	64	128	40	2048	-	256
Spansion	S34ML02G1 <sup>1)</sup>	V8.56.82	1/528	8	25	x1	2048	64	64	128	40	2048	CR,CP,MP	256
Spansion	S34ML04G1 <sup>1)</sup>	V8.56.82	1/528	8	25	x1	2048	64	64	128	80	4096	CR,CP,MP	512
Toshiba	TC58NVG3S0FTA10 <sup>1)</sup>	V8.34.51	4/512	8	25	x1	4096	232	64	256	80	4096	CR,CP,MP	1024
Toshiba	TH58NVG4S0FTAK0	V8.34.51	4/512	8	25	x2	4096	232	64	256	160	8192	CR,CP,MP	2048
Samsung	K9GAG08U0M	V8.37.55	4/512	8	25	x1	4096	128	128	512	100	4096	MP	2048
Samsung	K9F4G08U0D	TBD	~ 2012/11/30	-	-	-	-	-	-	-	-	-	-	-

1) Android ICS doesn't support nand whose size is less than 2GB.

**Terminology**

TERM		Meaning
PpB		Pages per Block
Function	CP	Cache Program
	MP	Multiplane Program
	IL	Interleave
	EIL	External Interleave
	RAND	S/W Randomizer
	RR	Read Retry

## Revision History

Date	Version	Description
2012-02-03	1.00	First Release
2012-03-09	1.01	Update Support NAND (H27U1G8F2B,H27U2G8F2C)
2012-04-02	1.02	Update Support NAND (H27UAG8T2B)
2012-05-10	1.03	Update Support NAND (K9F1G08U0D)
2012-08-22	1.04	Update Support NAND (TC58NVG3S0F, TH58NVG4S0F, TC58NVG4D2H, TC58NVG5D2H, TC58NVG6D2G, K9F2G08U0C, K9GAG08U0E, K9GBG08U0A, K9LCG08U0A, MT29F32G08CBACA, MT29F64G08CBAAA)
2012-10-09	1.05	Update Support NAND (K9GAG08U0M, THGVR1G5D1HTA00, THGVR1G6D1GTA00)
2012-11-06	1.06	Update Support NAND (S34ML01G1,S34ML02G1,S34ML04G1,MT29F64G08CBABA)

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